2SB1232 : PNP Epitaxial Planar Silicon Transistor 2SD1842 : NPN Triple Diffused Planar Silicon Transistor



2SB1232/2SD1842

100V/40A Switching Applications

Applications

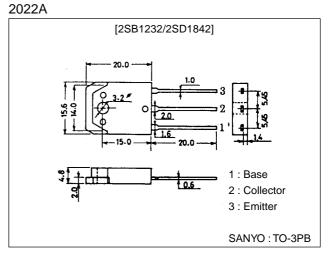
• Motor drivers, relay drivers, converters, and other general high-current switching applications.

Features

- · Large current capacity and wide ASO.
- · Low saturation voltage.

Package Dimensions

unit:mm



():2SB1232

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbo	Condition	Rating	Uni
Collector-to-Base Voltage	СВО		(∀)110	
Collector-to-Emitter Voltage	CEO		(∀)100	
Ethitter-to-Base Voltage	EBO		(₩)6	
Collector Current	С		(A)40	
Collector Current (Pulse)	CP		(A)65	
Base Current	В		(A)12	
Cellector Dissipation	С		31/0/	
		Tc=25°C	150	
Jjunction Temperature	Т		150	°C
Stoprage Temperature	Tst		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Sÿmbo	Condition	Ratings			Unit
			mjøn	tyc	ma	Unit
Collector Cutoff Current	СВО	V _{CB} =(-)100V, I _E =0			(A)0.	m
Emitter Cutoff Current	EBO	V _{EB} =(-)5V, I _C =0			(A)0.	m
DC Current Gain	h _{FE} 1V	CE=(-)2V, IC=(-)4A	50		140	
	h _{FE} 2V	CE=(-)2V, IC=(0-)16A	2			
Collector-to-Emitter Saturation Voltage	CE(sat)	I _C =(-)16A, I _B =&)1.6A			(₩)0.	
Base-to-Emitter Saturation Voltage	BE(sat)	I _C =(-)16A, I _B =\$-)1.6A			(₩)1.	

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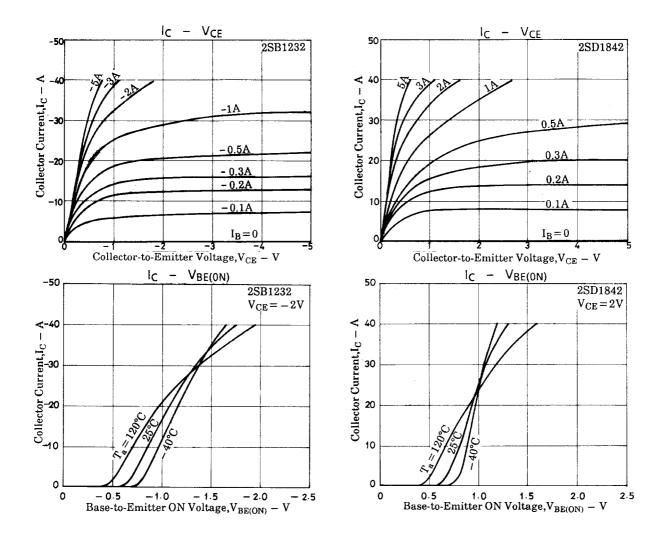
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

2SB1232/2SD1842

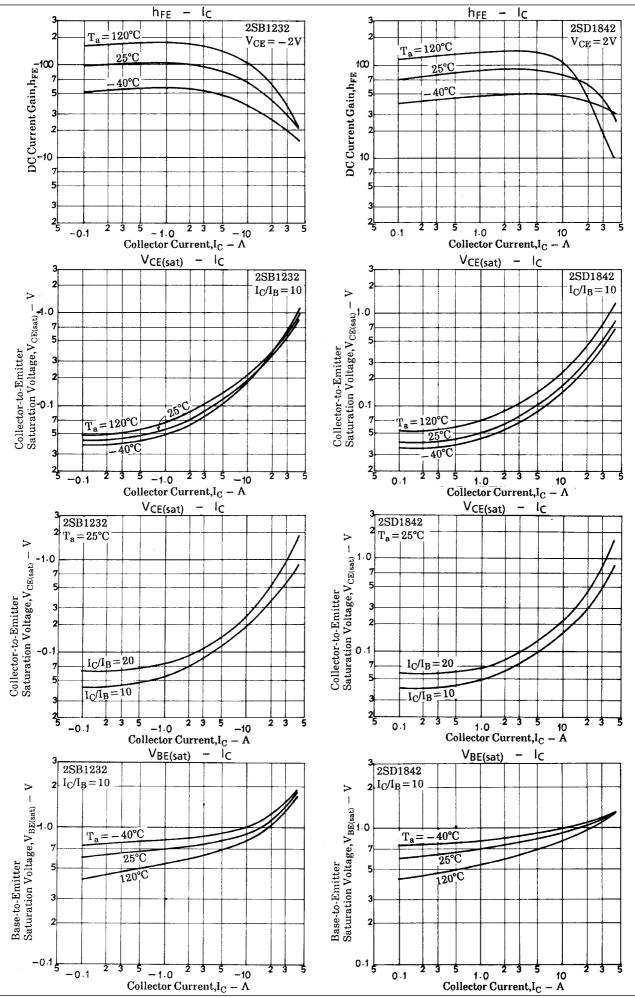
Parameter	Symbol	Conditions	Ratings			Unit
			mipn	tyc	ma	Unit
Collector-to-Base Breakdown Voltage	(BR)CBO	I _C =(-)1mA, I _E =0	(₩)11			
Collector-to-Emitter Breakdown Voltage	(BR)CEO	I _C =(−)5mA, R _{BE} =∞	(₩)100			
Ethitter-to-Base Breakdown Voltage	(BR)EBO	I _C =(-)1mA, I _C =0	(₩)			

 \ast : For the $h_{FE}1$ of the 2SB1232/2SD1842, specify at least two ranks in principle.

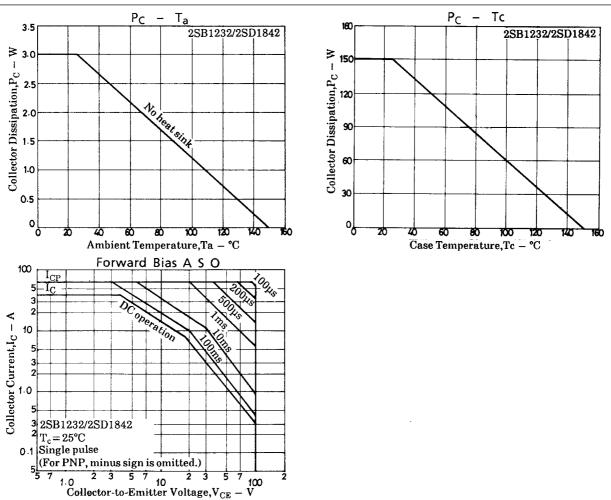
50 P 100 70 Q 14



2SB1232/2SD1842



No.3261-3/4



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